









SN74LV32A-Q1

SCLS516D - JULY 2003 - REVISED AUGUST 2023

SN74LV32A-Q1 Quadruple 2-Input Positive-Or Gate

1 Features

- Qualified for automotive applications
- Operation of 2-V to 5.5-V V_{CC}
- Max t_{pd} of 6.5 ns at 5 V
- Typical V_{OLP} (output ground bounce) <0.8 V at V_{CC} $= 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (output V_{OH} undershoot) >2.3 V at $V_{CC} = 3.3 \text{ V}, T_A = 25^{\circ}\text{C}$
- Support mixed-mode voltage operation on all ports
- I_{off} supports partial-power-down mode operation

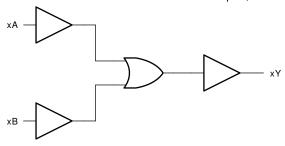
2 Description

These quadruple 2-input positive-OR gates are designed for 2-V to 5.5-V V_{CC} operation.

Package Information

PART NUMBER	PACKAGE ¹	PACKAGE SIZE ²
SN74LV32A-Q1	PW (TSSOP, 14)	5.00 mm × 6.4 mm

- For all available packages, see the orderable addendum at the end of the data sheet.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Logic Diagram, Each Gate (Positive Logic)



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3 Revision History

Changes from Revision C (January 2008) to Revision D (August 2023)

Page

 Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section



4 Pin Configuration and Functions

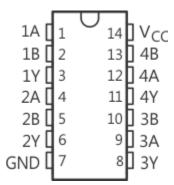


Figure 4-1. PW Package 14-Pin TSSOP Top View

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NO.	NAME	IYPE('')	DESCRIPTION
1	1A	I	1A input
2	1B	I	1B
3	1Y	0	1Y
4	2A	I	2A
5	2B	I	2B
6	2Y	0	2Y
7	GND	_	GND
8	3Y	0	3Y
9	3A	I	3A
10	3B	I	3B
11	4Y	0	4Y
12	4A	I	4A
13	4B	I	4B
14	V _{CC}	_	V _{CC}

⁽¹⁾ Signal Types: I = Input, O = Output, I/O = Input or Output



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)¹

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ¹		-0.5	7	V
Vo	Voltage applied to any output in the	Voltage applied to any output in the high-impedance or power-off state ¹			V
Vo	Output voltage range ^{1 2}	Output voltage range ^{1 2}		V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±25	mA
	Continuous current through V _{CC} or 0	SND		±50	mA
T _{stg}	Storage temperature	Storage temperature		150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ¹	±2000	V

⁽¹⁾ AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature (unless otherwise noted)¹

		MIN	MAX	UNIT
Supply voltage		2	5.5	V
	V _{CC} = 2 V	1.5		
Lligh level input veltage	V _{CC} = 2.3 V to 2.7 V	V _{CC} x 0.7		V
High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} x 0.7		V
	V _{CC} = 4.5 V to 5.5 V	V _{CC} x 0.7		
	V _{CC} = 2 V		0.5	
Low lovel input veltage	V _{CC} = 2.3 V to 2.7 V		V _{CC} x 0.3	V
Low-level input voitage	V _{CC} = 3 V to 3.6 V		V _{CC} x 0.3	V
	V _{CC} = 4.5 V to 5.5 V		V _{CC} x 0.3	
Input voltage		0	5.5	V
Output voltage		0	V_{CC}	V
	V _{CC} = 2 V		-50	μA
High level output ourrent	V _{CC} = 2.3 V to 2.7 V		-2	
nigh-level output current	V _{CC} = 3 V to 3.6 V		-6	mA
	V _{CC} = 4.5 V to 5.5 V		-12	
	V _{CC} = 2 V		50	μΑ
Low lovel output current	V _{CC} = 2.3 V to 2.7 V		2	
Low-level output current	V _{CC} = 3 V to 3.6 V		6	mA
	V _{CC} = 4.5 V to 5.5 V		12	
	High-level input voltage Low-level input voltage Input voltage	$\label{eq:localization} \text{High-level input voltage} \begin{tabular}{lll} $V_{\text{CC}} = 2 \text{ V}$ \\ $V_{\text{CC}} = 3 \text{ V to } 3.6 \text{ V}$ \\ $V_{\text{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 3 \text{ V to } 3.6 \text{ V}$ \\ \hline $V_{\text{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$ \\ \hline \end{tabular}$ Input voltage $\begin{tabular}{lll} $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 3.6 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 5.5 \text{ V}$ \\ \hline \end{tabular}$ High-level output current $\begin{tabular}{lll} $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 3.6 \text{ V}$ \\ \hline \end{tabular}$ Low-level output current $\begin{tabular}{lll} $V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$ \\ \hline $V_{\text{CC}} = 2.3 \text{ V to } 3.6 \text{ V}$ \\ \hline \end{tabular}$		$Supply \ voltage & 2 & 5.5 \\ High-level \ input \ voltage & V_{CC} = 2 \ V & 1.5 \\ \hline V_{CC} = 2.3 \ V \ to \ 2.7 \ V & V_{CC} \times 0.7 \\ \hline V_{CC} = 3 \ V \ to \ 3.6 \ V & V_{CC} \times 0.7 \\ \hline V_{CC} = 4.5 \ V \ to \ 5.5 \ V & V_{CC} \times 0.7 \\ \hline V_{CC} = 2.3 \ V \ to \ 5.5 \ V & V_{CC} \times 0.7 \\ \hline V_{CC} = 2 \ V & 0.5 \\ \hline V_{CC} = 2 \ V & V_{CC} \times 0.3 \\ \hline V_{CC} = 3 \ V \ to \ 3.6 \ V & V_{CC} \times 0.3 \\ \hline V_{CC} = 3 \ V \ to \ 5.5 \ V & V_{CC} \times 0.3 \\ \hline Input \ voltage & 0 & 5.5 \\ \hline Output \ voltage & 0 & V_{CC} \\ \hline High-level \ output \ current & V_{CC} = 2 \ V & -50 \\ \hline V_{CC} = 3 \ V \ to \ 5.5 \ V & -12 \\ \hline V_{CC} = 3 \ V \ to \ 5.5 \ V & -12 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & -50 \\ \hline V_{CC} = 3 \ V \ to \ 5.5 \ V & -12 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 2 \ V & 50 \\ \hline V_{CC} = 3 \ V \ to \ 2.7 \ V & 2 \\ \hline V_{CC} = 3 \ V \ to \ 3.6 \ V & 6 \\ \hline \end{array}$

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⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value is limited to 5.5-V maximum.

over operating free-air temperature (unless otherwise noted)¹

			MIN	MAX	UNIT
		V _{CC} = 2.3 V to 2.7 V		200	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V		100	ns/V
		V _{CC} = 4.5 V to 5.5 V		20	
T _A	Operating free-air temperature		-40	105	°C

All unused inputs of the device must be held at V_{CC} or GND for proper device operation. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, SCBA004.

5.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

	THERMAL METRIC(1)	PW (TSSOP)	UNIT
	THERMAL METRIC	14 PINS	ONIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	113	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

5.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT	
		I _{OH} = -50 μA	2 to 5.5 V	V _{CC} - 0.1				
.,	Lligh lovel output voltage	I _{OH} = -2 mA	2.3 V	2			V	
V _{OH}	High level output voltage	I _{OH} = -6 mA	3 V	2.48			V	
		I _{OH} = -12 mA	4.5 V	3.8				
		I _{OL} = 50 μA	2 to 5.5 V			0.1		
. ,	Low level output voltage	I _{OL} = 2 mA	2.3 V			0.4	V	
V_{OL}		I _{OL} = 6 mA	3 V			0.44		
		I _{OL} = 12 mA	4.5 V			0.55		
II	Input leakage current	V _I = 5.5 V or GND	0 to 5.5 V			±1	μA	
I _{CC}	Supply current	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20	μA	
I _{off}	Input/Output Power-Off Leakage Current	V _I or V _O = 0 to 5.5 V	0			5	μΑ	
C	Innut Canacitanas	V = V or CND	3.3 V		3.3		"F	
Ci	Input Capacitance	$V_I = V_{CC}$ or GND	5 V		3.3		pF	

5.6 Switching Characteristics, V_{CC} = 2.5 V ±0.2 V

over recommended operating free-air temperature range, V_{CC} = 2.5 V ±0.2 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T,	_A = 25°C		MIN	MAX	UNIT
PARAWETER		10 (001701)	CAPACITANCE	MIN	TYP	MAX	WIIN WAX	ONII	
t _{pd}	A or B	Y	C _L = 50 pF		9.6	16.2	1	20	ns

5.7 Switching Characteristics, V_{CC} = 3.3 V ±0.3 V

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T _A = 25°C		MIN MAX		UNIT	
	PARAMETER	PROM (INFO1)	10 (001701)	CAPACITANCE	MIN	TYP	MAX	IVIIN IVIAA	UNII	
t	pd	A or B	Y	C _L = 50 pF		6.9	11.4	1	13	ns



5.8 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range, V_{CC} = 5 V ±0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD	T _A = 25°C			MAX	UNIT	
PARAMETER	PROWI (INFOT)	10 (001701)	CAPACITANCE	MIN	TYP	MAX	IVIIIV II	IVIAA	UNII
t _{pd}	A or B	Y	C _L = 50 pF		4.9	7.5	1	8.5	ns

5.9 Noise Characteristics

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.2	0.8	
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.1	-0.8	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.1		V
V _{IH(D)}	High-level dynamic input voltage	2.31			
V _{IL(D)}	Low-level dynamic input voltage			0.99	

(1) Characteristics are for surface-mount packages only.

5.10 Operating Characteristics

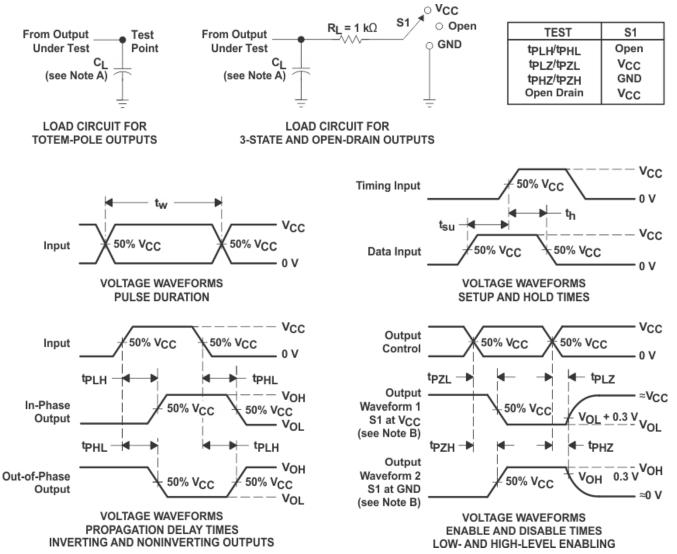
 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
	C _{nd} Power dissipation capacitance	C ₁ = 50 pF, f = 10 MHz	3.3 V	9.5	pF
1	rower dissipation capacitance	C _L = 50 pr, 1 = 10 MHz	5 V	11.5	

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6 Parameter Measurement Information



- C_I includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns. $t_f \leq 3$ ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and tPZH are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 6-1. Load Circuit and Voltage Waveforms



7 Detailed Description

7.1 Overview

These quadruple 2-input positive-OR gates are designed for 2-V to 5.5-V V_{CC} operation.

The SN74LV32A performs the Boolean function Y = A + B or $Y = \overline{A \cdot B}$ in positive logic.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

7.2 Functional Block Diagram

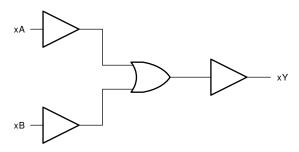


Figure 7-1. Logic Diagram, Each Gate (Positive Logic)

7.3 Device Functional Modes

Table 7-1. Function Table

INPUT	OUTPUT ⁽²⁾				
Α	В	Y			
Н	Х	Н			
Х	Н	Н			
L	L	L			

- (1) H = High Voltage Level, L = Low Voltage Level, X = Don't Care
- (2) H = Driving High, L = Driving Low, Z = High Impedance State

8 Device and Documentation Support

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LV32A-Q1	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LV32ATPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(LV32AT, LV32ATQ)	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LV32A-Q1:

PACKAGE OPTION ADDENDUM

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Catalog: SN74LV32A

● Enhanced Product : SN74LV32A-EP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

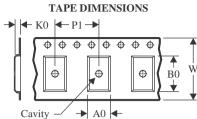
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	· · · · · · · · · · · · · · · · · · ·
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV32ATPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV32ATPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV32ATPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LV32ATPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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